

LA7449, 7449M

Video Signal Processing IC for VHS VCR Systems

Overview

The LA7449, 7449M is a video signal processing single-chip IC that handles the PAL-G, B and I, 4.43 NTSC, MESECAM and NAP-G, B and I formats. IC internal trimming is used to make the LA7449, 7449M is completely adjustment free, and in combination with a special-purpose CCD (the LC89970, 89970M) it provides a significant reduction in external components, including the glass delay line. Thus the LA7449, 7449M can significantly reduce the signal processing board manufacturing costs. Furthermore, the LA7449, 7449M supports the NAP format (NTSC to PAL conversion) that is poised to become widespread in Europe, China and other markets.

Features

· Completely adjustment free

The AGC, carrier, deviation, and PB-Y level are adjustment free.

The YC record current can also be made adjustment free by using the LA7411, 7416 as the head amplifier.

- Support for NAP and PAL color array correction
 Full modulation using a balanced modulator allows
 playback and conversion to PAL format of NTSC
 signals recorded on tape.
- Crosstalk exclusion in combination with a specialpurpose CCD

Crosstalk can be excluded without using a glass delay line by combining the LA7449, 7449M with a special-purpose CCD (the LC89970, 89970M).

- Minimal number of external components New built-in components:
 - Detail enhancer CR
 - C-trap in the Y low-pass filter
 - Playback C low-pass filter
- · High performance and multiple functions

Linear phase picture controller

Double high-pass noise canceller, high-speed AFC, DCC

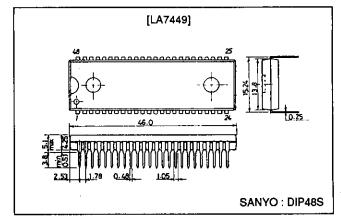
New built-in functions

- NAP circuit
- AVNS (advanced vertical noise suppresor)
- Automatic QH insertion
- FM AGC
- Miniature package (48-pin QIP or DIP)

Package Dimensions

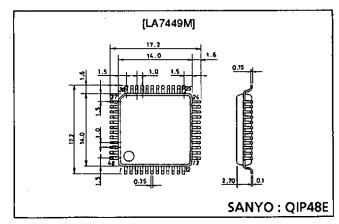
unit: mm

3149-DIP48S



unit: mm

3156-QIP48E



Functions

All VHS format VCR signal processing functions

	Lumina	ince	Chrominance				
R∕P	Video amp. Feed back clamp Main LPF YNR (AVNS) VCA Sync separator 4.2 V regulator		4.43 BPF ACC amp. ACC det. Main converter 1.3 M LPF VXO/XO Side lock det. 3rd lock protector	Half H killer BGP generator Killer det. VCO Phase shifter Sub converter 5.06 BPF			
REC	Video AGC amp. Video AGC det. Pre LPF Detail enhancer 1/2 f _H carrier shift	NL emphasis Main emphasis White/dark clip FM modulator	Pre amp. Burst emphasis (NTSC) Killer APC det. AFC det.	Burst gate amp.			
РВ	FM AGC amp. FM AGC det. Double limiter FM demodulator Sub LPF Double high pass noise canceller QV/QH/character insert Main de-emphasis DOC	Drop out det. NL de-emphasis Picture control Y/C mix	Pre amp. Burst de-emphasis (NTSC) PB amp. Killer NAP PAL burst sequence - Compensator Carrier balancer Burst gate amp.	APC det. ID det. DCC Trick det. DPLL			

Specifications

Pin numbers are for the LA7449M.

Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		7.0	٧
Allowable power dissipation	Pd max	Ta ≤ 65°C*	1350*	mW
Operating temperature	Topr		-10 to +65	°C
Storage temperature	Tstg		-40 to +150	•¢_

Note: * When mounted on a 70 mm by 65 mm, 1.5 mm thickness Bakelite board. The value for the DIP package is 1150 mW.

Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC}		5.0	٧
Operating supply voltage	V _{CC} op		4.8 to 5.2	V

Operating Characteristics at $Ta = 25^{\circ}C$, $V_{CC} = 5.0 \text{ V}$

Parameter	Symbol	Conditions	min	typ	max	Unit
[Record Mode Y System]						_
Record mode current drain	ICCR	Input: 1,0 Vp-p video signal	100	130	160	mA
EE output level 1	V _{EE} 1	Input: 50 Hz system 1.0 Vp-p video signal	1.95	2.05	2.15	Vp-p
AGC characteristics 1	AGC1	Input: 50 Hz system 2.0 Vp-p video signal	2.05	2.15	2.25	Vp-р
AGC characteristics 2	AGC2	Input: 50 Hz system 0.5 Vp-p video signal	1.90	2.00	2.10	Vp-p
AGC characteristics 3	AGC3	Input: 50 Hz system with only SYNC increased 6 dB	555	615	695	mVp-p
AGC characteristics 4	AGC4	Input: 50 Hz system with only SYNC decreased 6 dB	370	410	450	mVp-p
Sync separator output level	V _{SYR}	The SYNC-OUT output pulse wave height	3.9	4.1	4.3	V
Sync separator output pulse width	PWSYR	The SYNC-OUT output pulse width	4.0	4.3	4.6	μs
Sync separator output prerecord delay time	ΔT _{SYR}	The SYNC-OUT delay time	0.9	1.1	1.3	μѕ
Sync separator threshold level	TH _{SYR}			-20	-15	dB

Continued on next page.

LA7449, 7449M

Continued from preceding page.

Parameter	Symbol	Conditions	min	Nin	max	Unit
[Record Mode Y System]	Зуппон	Conditions	111111	lyp	IIIdA	1
Pseudo-H insertion level	ΔHD _B	With 2.7 V applied to T14A	-400	-300	-200	mV
White insertion level	ΔΝΗ _R	With 1.3 V applied to T14A	100	250	400	mV
VCA detection voltage		Will 1.5 V applied to 114A	3.00	3.20	3.40	"V
Record YNR operation EP/LP	V _{VCA}	January 50 Lts system standard polar has signal	10	12	14	
	V _{R-YNR1}	Input: 50 Hz system standard color bar signal	-0.5	0.0	+0.5	mVp-p dB
Y-LPF frequency characteristics 1	YLPF1	The 1 MHz attenuation with respect to 500 kHz		·		qB
Y-LPF frequency characteristics 2	YLPF2	The 2 MHz attenuation with respect to 500 kHz	-1.0	0.0	+1.0	dB
Y-LPF frequency characteristics 3	YLPF3	The 3 MHz attenuation with respect to 500 kHz	-2.5	0.5	+1.0	dB
Y-LPF frequency characteristics 4	YLPF4	The 4.43 MHz attenuation with respect to 500 kHz		4.0	-25	
FM modulator output level	V _{FM}	No input	1.0	1.2	1.4	Vp-p
Carrier frequency 1	F _{FM1}	50 Hz system	3.7	3.6	3.9	MHz
FM modulator output 2nd harmonic distortion	H _{MOD}			-40	-35	dB
Deviation 1	DEV1	50 Hz system	0.95	1.00	1.05	MHz
FM modulator linearity	LMOD		-2	0	2	%
1/2 f _H carrier shift	ĊS		6.5	7.8	9.1	kHz
Emphasis gain	G _{EMP}	Input: 0.5 Vp-p, 10 kHz sine wave	0.5	0.0	0.5	dB
Detail enhancer characteristics 1	G _{DET1}	Input: 316 mVp-p, 2 MHz sine wave	1.6	1.9	2.6	dB
Detail enhancer characteristics 2	G _{DET2}	Input: 100 mVp-p, 2 MHz sine wave	3.1	4.1	5.1	dB
Detail enhancer characteristics 3	G _{DET3}	Input: 31.6 mVp-p, 2 MHz sine wave	5.3	6.3	7.3	dB
NL emphasis characteristics 1	G _{NLEMP1}	Input: 500 mVp-p, 2 MHz sine wave	0.5	1.4	2.3	dB
NL emphasis characteristics 2	G _{NLEMP2}	Input: 158 mVp-p, 2 MHz sine wave	2.6	3.8	5,2	dB
NL emphasis characteristics 3	G _{NLEMP3}	Input: 50 mVp-p, 2 MHz sine wave	4.9	6.4	7.9	dB
Main emphases characteristics 1	G _{ME1}	Input: 100 mVp-p, 500 kHz sine wave	4.9	5.2	5.5	dB
Main emphases characteristics 2	G _{ME2}	Input: 100 mVp-p, 2 MHz sine wave	13.1	13.6	14.1	dB
White clipping level		Input: 1.0 Vp-p, white 100% video signal	186	195	204	%
Dark clipping level	Lwc	Input: 1.0 Vp-p, white 100% video signal	-55	-50	_45	%
[Playback Mode Y System]	LDC	input. 1.0 Vp-p, writte 100% video signal	-55	-30		L
Playback mode current drain	1		135	160	185	l mA
· · ·	ICCP		0.72	0.85	0.98	ms
Dropout compensation time	TDOC	Cillian				dB
DOC loop gain	GDOC	5H later	-1.0	0.0	+1.0	
Playback Y level	V _{VOUT}	For playback of an FM signal with a 1.0 MHz deviation	1.95	2.05	2.15	Vp-p
FM demodulator linearity	L _{DEM}	2, 4, 6 MHz	-3.5	0.0	+3.5	%
Demodulation sensitivity	SDEM		0.47	0.52	0.57	V/MHz
Carrier leakage	CL	Input: 4 MHz, 600 mVp-p		-4 0	-35	dB
Playback YNR characteristics LP/EP	G _{P-YNR1}	Input: 50% white + CW	-2.5			dB
NL de-emphasis characteristics 1	G _{NLDE1}	Input: 158 mVp-p, 2 MHz sine wave	-6.0	-5.0	-4.0	dB
NL de-emphasis characteristics 2	G _{NLDE2}	Input: 50 mVp-p, 2 MHz sine wave	-10.5	-9.0	-7.5	dB
Double noise canceller characteristics 1	GWNC1	Input: 158 mVp-p, 2 MHz sine wave	-1.8	-1.3	-0.8	dB
Double noise canceller characteristics 2	G _{WNC2}	Input: 50 mVp-p, 2 MHz sine wave	-6.2	-5.2	-4.2	dB
Double noise canceller characteristics 3	G _{WNC3}	Input: 15.8 mVp-p, 2 MHz sine wave	-11.7	-10.7	-8.7	dB
PIC-CTL hard response	G _{PH1}	Input: 50% video + sine wave f = 1 MHz, 158 mVp-p	4.5	5.5	6.5	dB
characteristics 1 PIC-CTL hard response	G _{PH2}	Input: 50% video + sine wave f = 2 MHz, 158 mVp-p	8.0	9.0	10.0	dB
characteristics 2 PIC-CTL soft response	G _{PS1}	Input; 50% video + sine wave f = 1 MHz, 158 mVp-p	-4.5	-3.5	-2.5	dB
characteristics 1 PIC-CTL soft response	G _{PS2}	Input: 50% video + sine wave f = 2 MHz, 158 mVp-p	-9.0	-7.0	-5.0	dB
characteristics 2 Pseudo-V insertion level	ΔVDp	With 5 V applied to T14A	-150	-50	+50	mV
(playback) Pseudo-H insertion level			– 400	-300	-200	mV
(playback)	ΔHDp	With 2.7 V applied to T14A		-300	-200	

Continued on next page.

LA7449, 7449M

Continued from preceding page.

		· · · · · · · · · · · · · · · · · · ·				
Parameter	Symbol	Conditions	min	typ	max	Unit
[Record Mode Y System]						
White insertion level (playback)	ΔWH _P	With 1.3 V applied to T14A	100	250	400	mV
Sync separator output level	V _{SYP}	The SYNC-OUT output pulse wave height	3.9	4.1	4.3	V
Sync separator output pulse width	PWSYP	The SYNC-OUT output pulse width	4.2	4.5	4.8	μs
Sync separator output pre-record delay time	ΔT _{ŞYP}		1,4	1.6	1.8	μѕ
4.2 V regulator voltage	V _{REG}		4.0	4.2	4.4	V
[Record Mode Chrominance Syste	m]		· · · · · · · · ·	<u> </u>	······································	
Chrominance low band conversion output burst level	V _{OR-38}	Input: PAL/GBI standard color bar signal, 1 Vp-p	150	190	230	mVp-p
VXO oscillator level 1	V _{VXO-R1}	Input: PAL/GBI standard color bar signal, 1 Vp-p	300	500	700	mVp-p
Record ACC characteristics 1	ACC _{-R1}	With only the chrominance signal level increased 6 dB		+0.2	+0.6	dB
Record ACC characteristics 2	ACC.R2	With only the chrominance signal level decreased 6 dB	-0.5	-0.1		dB
ACC killer on input level	V _{ACCK-ON}		-	-26		dB
ACC killer on output level	V _{O-ACCK}			-60	-50	dB
ACC killer recovery input level	V _{ACCK-OFF}			-20		dB
VXO control sensitivity	S _{VXO}		1.3	3.2	5.1	Hz/m
APC pull-in range 1	Δf _{APC1}		350			Hz
APC pull-in range 2	Δt _{APC2}				-350	Hz
BGP delay time	t _D	Input: PAL/GBI standard color bar signal, 1 Vp-p	3.1	3.4	3.7	μѕ
BGP pulse width	tw		4.7	4.9	5.1	μз
AFC pull-in range 1	ΔÍ _{AFC1}		+1.0	+7.0		kHz
AFC pull-in range 2	Δf _{AFC2}			-3.7	-1.0	kHz
[Playback Mode Chrominance Sys						
Video output burst fevel	V _{OP-11}	SP mode, input: burst 30 mVp-p	255	300	345	mVp-p
Pin 25 output burst level	V _{OP-25}	SP mode, input: burst 30 mVp-p	195	230	265	mVp-p
Playback ACC characteristics 1	ACC.P1	With the chrominance level increased 6 dB		+0.5	+0.8	dB
Playback ACC characteristics 2	ACC_P2	With the chrominance level decreased 6 dB	-0.8	-0.5		dB
Playback killer on input level	V _{ACK-P}		-40	-32	-25	dB
Playback killer on chrominance output level	VOACK-P			-44	–40	dB
Main converter carrier leakage	CLP	The 5.06 MHz carrier leakage component		-40	-33	dВ
Burst de-emphasis level NT	G _{BD}	NTSC mode	-5.25	~5.0	-4.75	dB
Playback XO output level 1	V _{XO-P1}	-	300	450	600	mVp-p
Playback XO oscillator frequency deviation	ΔίχΟ	ΔfXO = f - 4.433619 (MHz)	-9	0	+9	Hz
SLD detector current 1	I _{SLD1}			170		μΑ
SLD detector current 2	I _{SLD2}			170		Aιί
NTSC playback burst output level	V _{BNT}	NTSC mode	255	300	345	mVp-p
NTSC to PAL conversion - V axis burst level	VB-NAP		-1.0	0.0	+1,0	dB
NTSC to PAL conversion burst level ratio	ΔB-NAP		-2.0	0.0	+2.0	dB
						

L7449M Control Pin Table

Pin No.		Control function	L			М	Н			
3	R/P	Edit	3				3.8 VD	3.8 VDC or more		
5	R/P	YNR (AVNS)-CTL	1.0 VDC to less YNR-off		1.5 to 2.5 VDC YNR-CTL		3.5 VD YNR (s	C or more strong)		
	R	****					3.9 VD	C or more		
6	Р	N, C, CTL	1.5 VDC or less N, C-off		2.0 to 3.0 VDC N, C-CTL					
12	R/P	C-rotary	0 to 1.9 VDC Low CH			2.3 VDC or mor High CH	e			
14	Р	QV/QH CHARA. INS	0.8 VDC or less Through	1.2 to 2 CHARA		2.6 to 3.3 VDC Pedestal insert		3.7 VDC or more QV insert		
15	Р	Auto QH INS on	Pull down by 3.9 kΩ							
18	R/P	N. Lon (weak)	0.6 VDC or less N. Loff		1.0 to 3.0 VDC N. Lon		3.9 VD N. Lo	C or more ff		
	R	Detail-ENHA	Normal		Weak and f _C do	wn	Norma	l		
22	R/P	EP/LP/SP	1.2 VDC or less SP		2.0 to 2.7 VDC LP		3.9 VD EP	C or more		
23	R	SP carrier shift stop						C or more rier shift stop		
24	Р	NAP	1.2 VDC or less Through		2.0 to 2.7 VDC Balanced-mod output		3.3 VDC or more NAP-on			
26	R/P	NT/MESEC/PAL	1.2 VDC or less PAL		2.0 to 2.7 VDC MESEC		3.9 VDC or more NTSC			
29	Р	Trick					3.9 VD	C or more		
44	P	DOC-off					4.1 VD	C or more		
48	R/P	РВ-Н					4.0 VD	C or more		

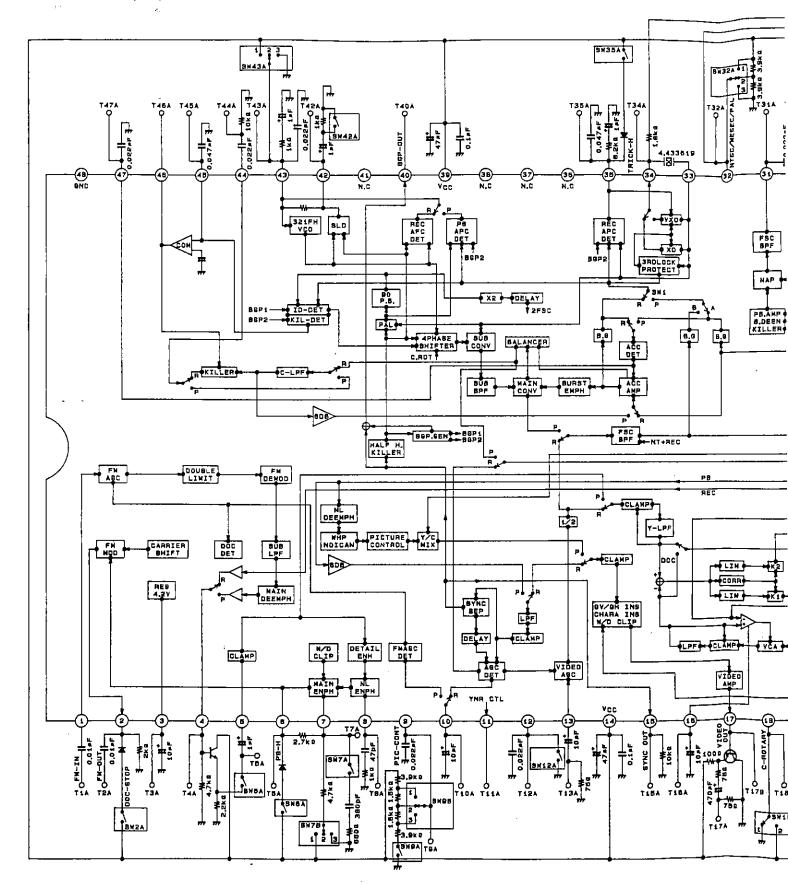
Note: Do not allow pin 3 to fall under 1.5 V. (The chip will enter test mode.)

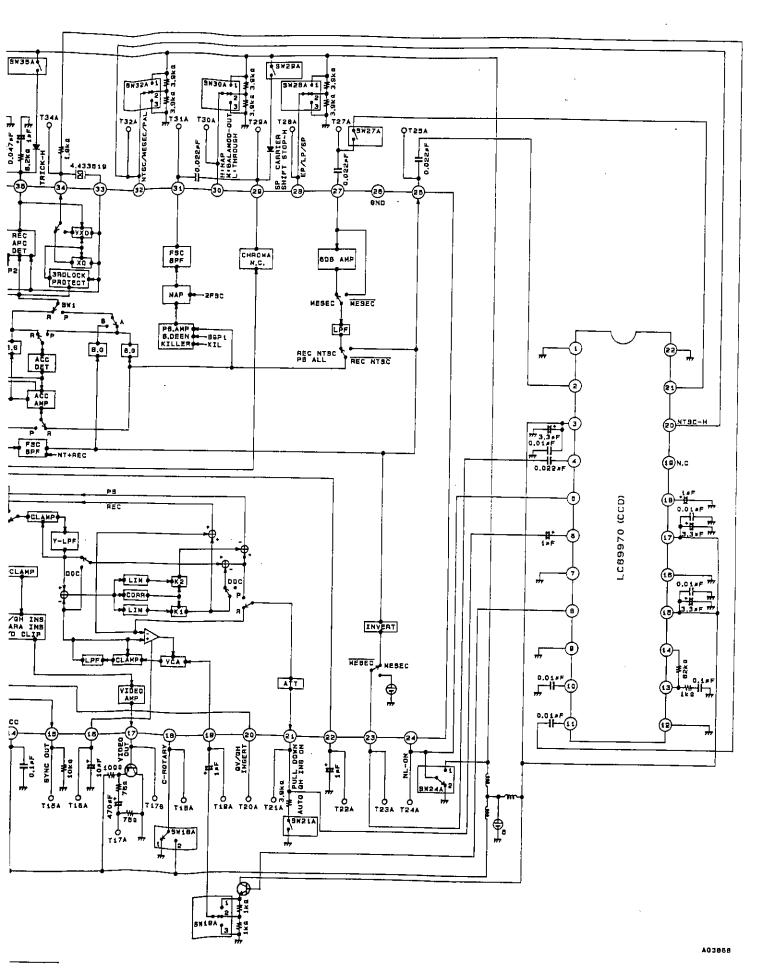
Function Control in each of the LA7449M Operating Modes

								YNR		N	IL.	De	tail enhan	cer		NC			
		Edit	Edit Pin 5 control		Pin 18 control		Pin 6 control (with pin 18 control L/H)			Pin 6 control			PIC-CTL	1/2 f _H carrier shift					
			L	М	н	Ļ/H	М	L	М	Н	L	М	Н		SIRIL				
REC	SP	On	Off	Off	Off	Off	On	Off	Variable	Center	_	_	_	_	O (X)				
	٦	3F	Off	Off	Off	Off	Off	On	Off	Variable	Center	_	_	-	_	S O			
	LP EP	LP	On	Off		K1 = 0.2 K2 = 0.0	On	On	Off	Variable	Center	_	_	_	_	0			
		Off	Off		K1 = 0.5 K2 = 0.0	On	On	Off	Variable	Center	_	_	_	_	0				
	SP	On			K1 = 0.5 K2 = 0.0	Off	On	-		I.	Off	Variable	Center	Center					
PB	Sr.	Off			K1 = 0.5 K2 = 0.0	Off	On	-	_	-	Off	Variable	ble Center	0	_				
	ĹР	On			K1 = 0.5 K2 = 0.5	On	Oπ		_	_	Off	Variable	Center	Center	-				
	EP	Off		1	K1 = 0.5 K2 = 0.5	On	On		_		Off	Variable	Center	0					

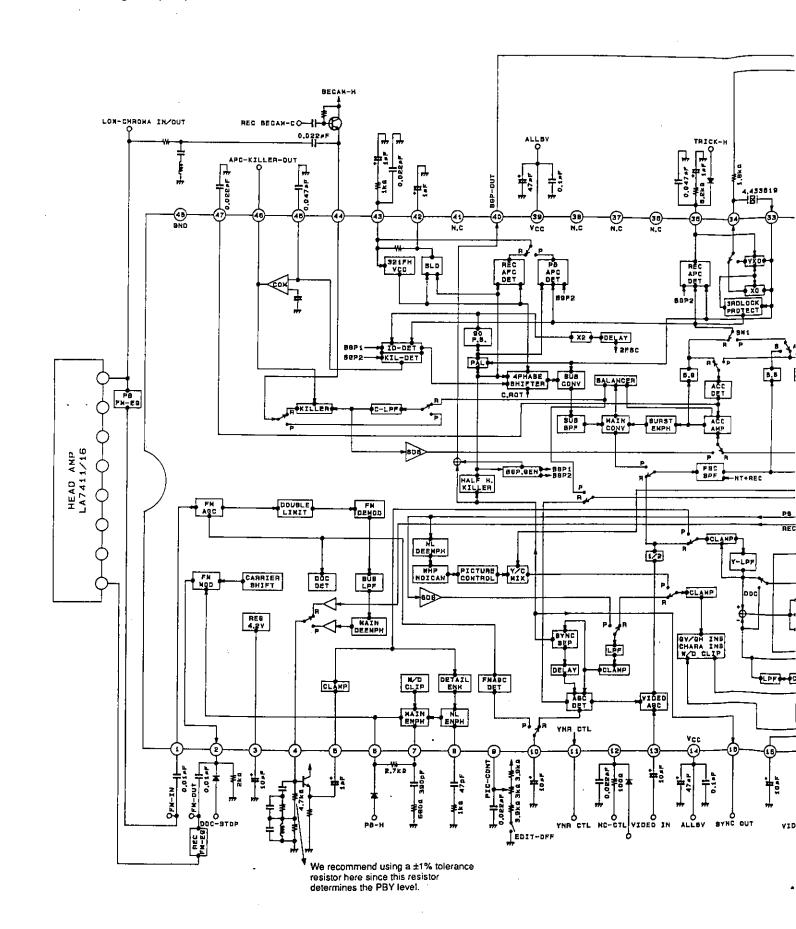
Note: 1. K1 is the YNR coefficient, K2 is the LNC coefficient
2. Use the 1/2 f_H carrier shift entries in parentheses when pin 23 is high.
3. The detail enhancer is off when pin 18 is at the middle level.

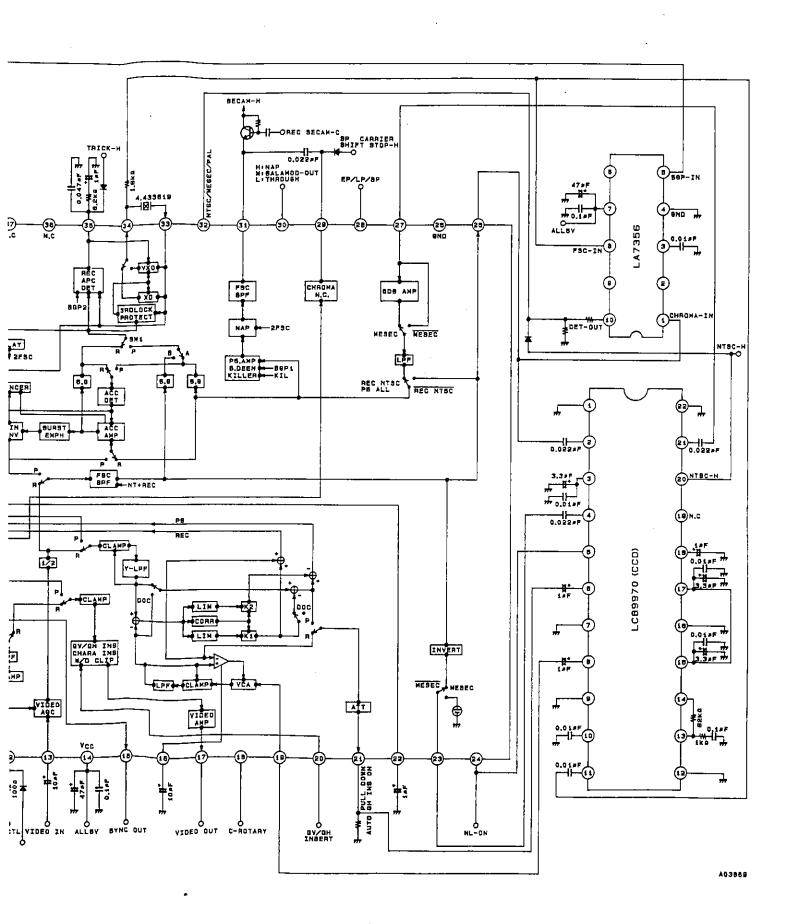
_A7449 Test Circuit (DIP)

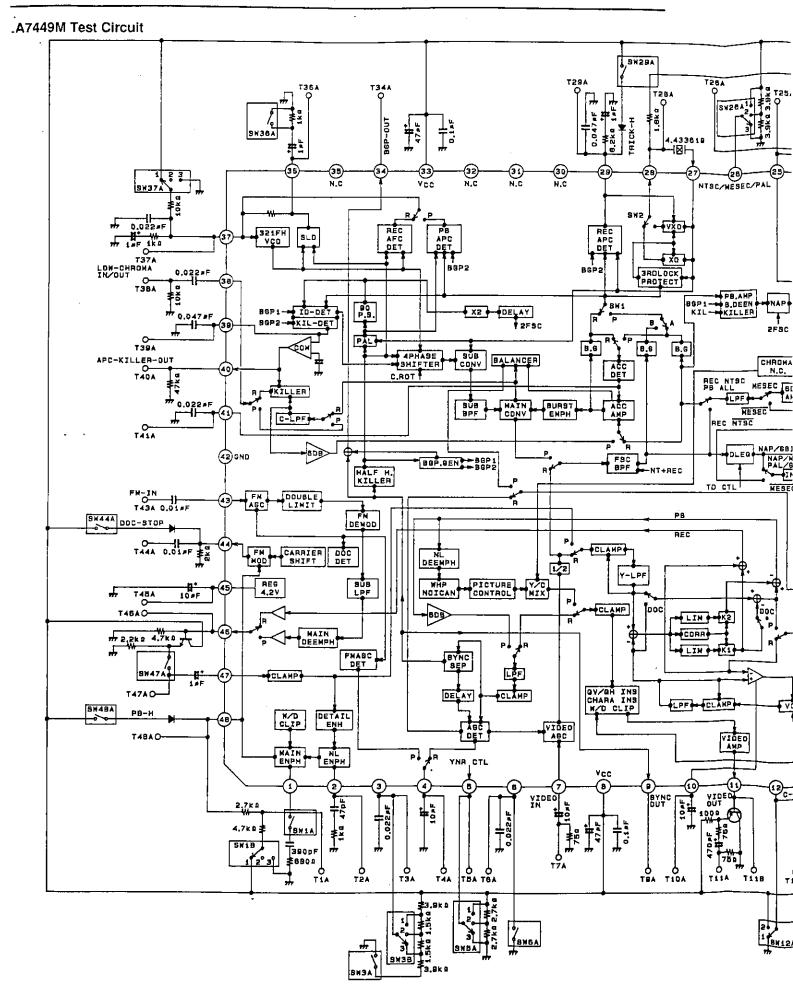


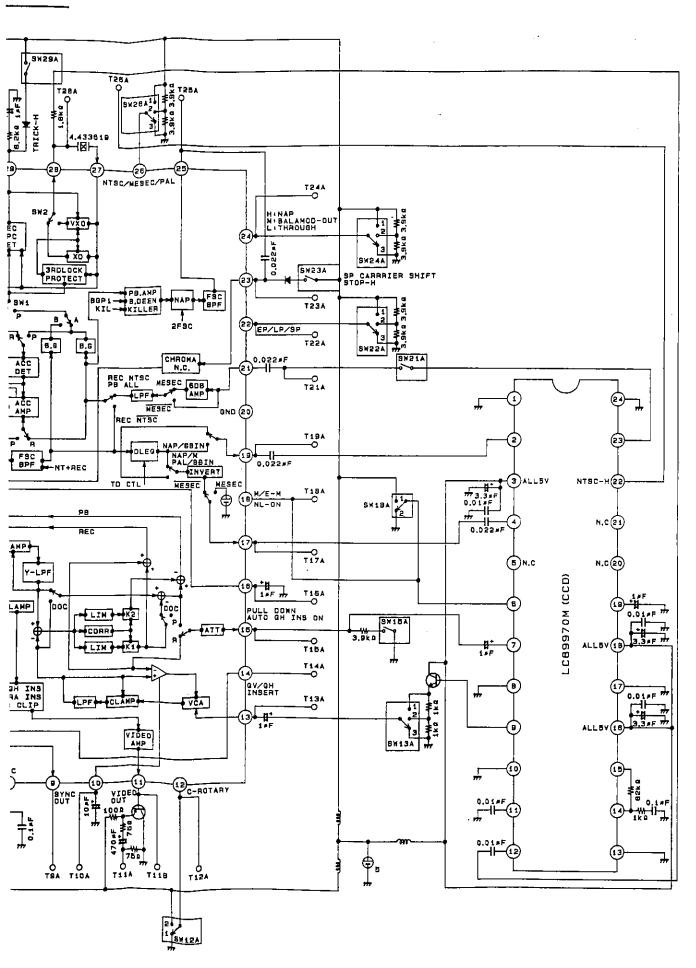


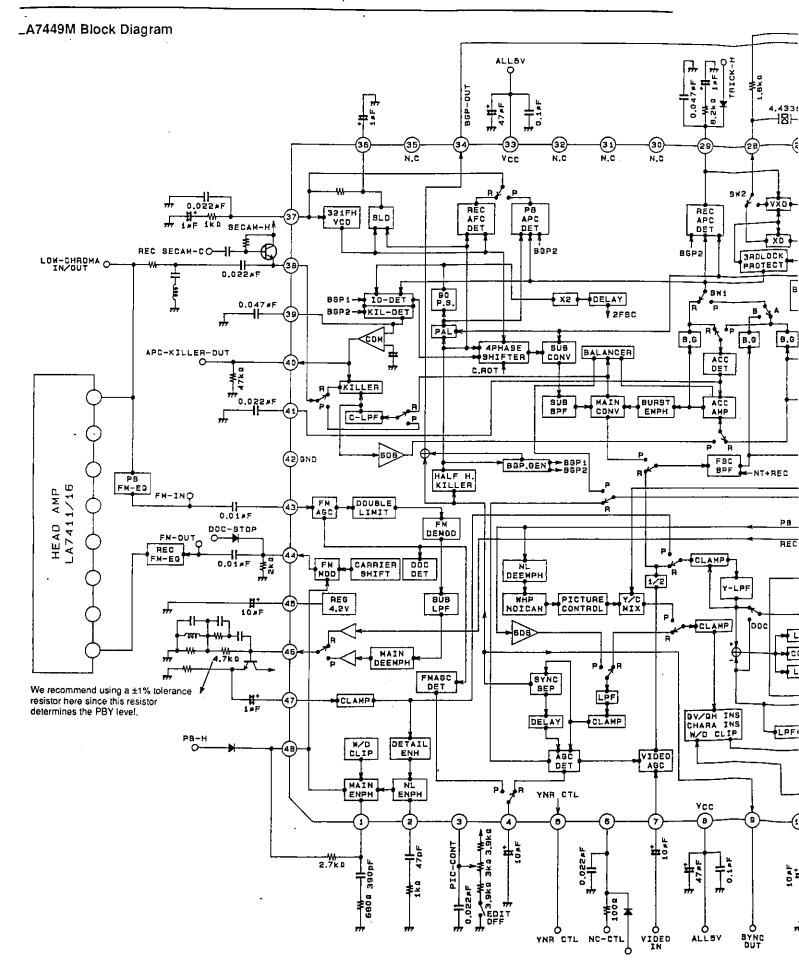
A7449 Block Diagram (DIP)

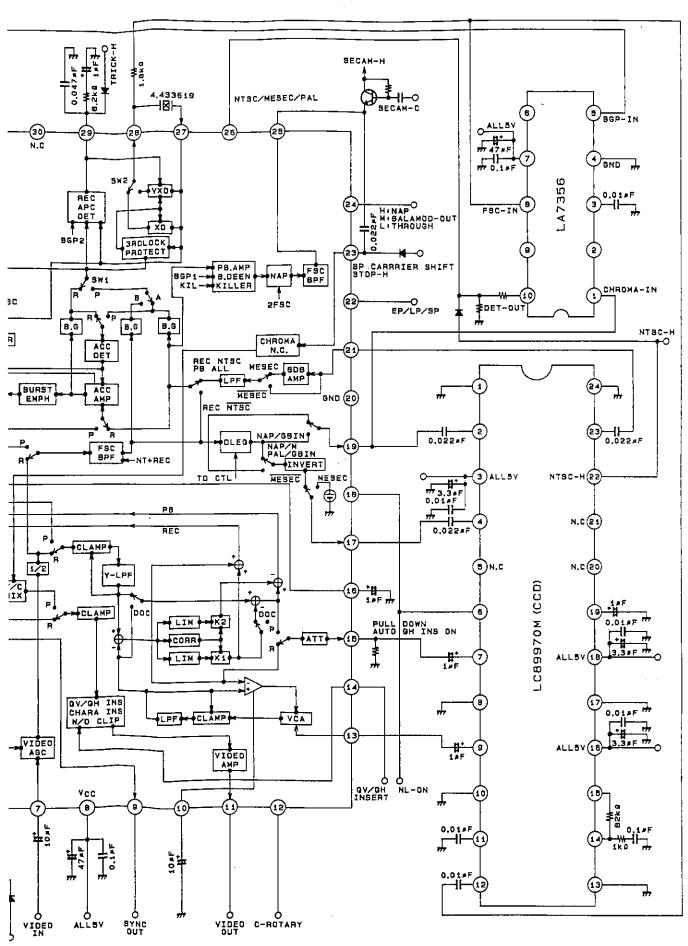












- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
 - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of June, 1995. Specifications and information herein are subject to change without notice.